

STYLE 1:

PIN1 = COLLECTOR (2X)

2 = BASE (4X)

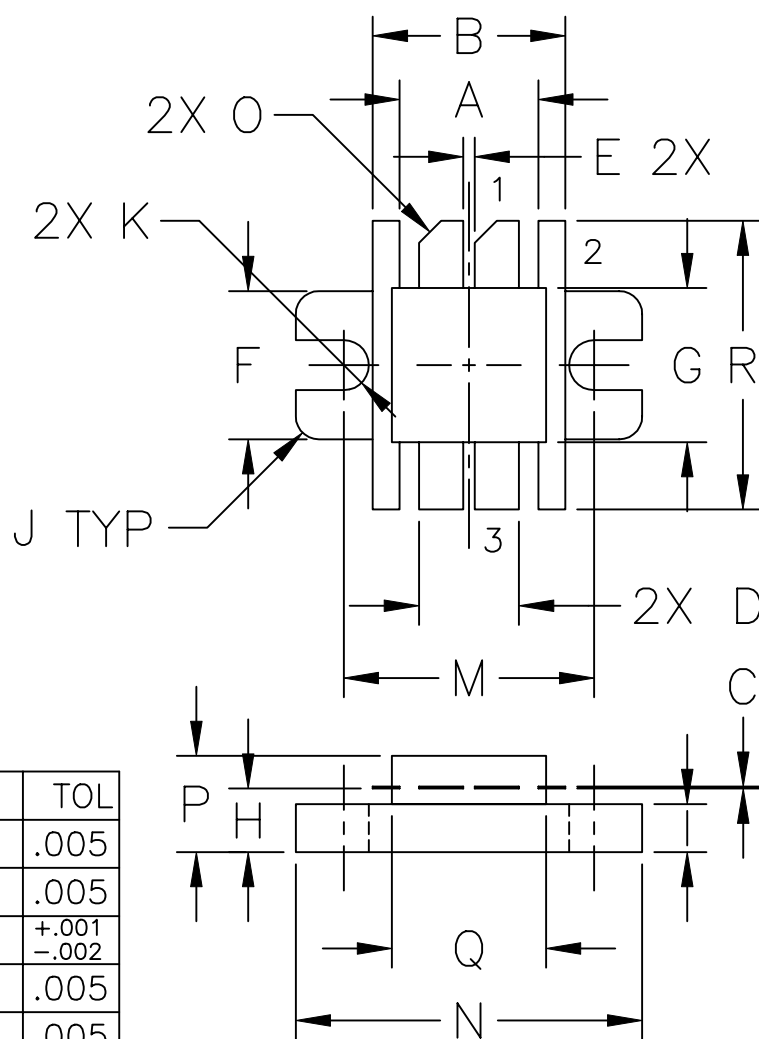
3 = EMITTER (2X)

STYLE 2:

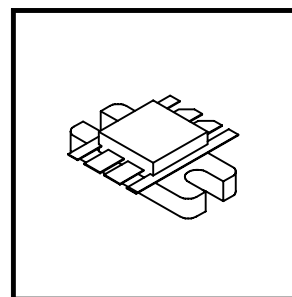
PIN1 = COLLECTOR (2X)

2 = EMITTER (4X)

3 = BASE (2X)



DIM	MILLIMETER	TOL	INCHES	TOL
A	9.14	.13	.360	.005
B	12.70	.13	.500	.005
C	0.13	.03 .05	.005	+.001 -.002
D	6.86	.13	.270	.005
E	0.76	.13	.030	.005
F	9.78	.13	.385	.005
G	10.16	.13	.400	.005
H	4.19	.13	.165	.005
I	3.17	.13	.125	.005
J	1.52R	.13	.060R	.005
K	1.65R	.13	.065R	.005
M	16.51	.13	.650	.005
N	22.86	.13	.900	.005
O	45°	5°	45°	5°
P	6.86	REF	.270	REF
Q	10.77	.13	.424	.005
R	19.05	.25	.750	.010



GHz TECHNOLOGY
RF - MICROWAVE SILICON POWER TRANSISTORS

DWG NO.

55JT